



# OPT209

## PHOTODIODE WITH ON-CHIP AMPLIFIER

### FEATURES

- PHOTODIODE SIZE: 0.090 x 0.090 inch (2.29 x 2.29mm)
- 1M $\Omega$  FEEDBACK RESISTOR
- HIGH RESPONSIVITY: 0.45A/W (650nm)
- LOW DARK ERRORS: 2mV
- BANDWIDTH: 16kHz
- WIDE SUPPLY RANGE:  $\pm 2.25$  to  $\pm 18$ V
- LOW QUIESCENT CURRENT: 400 $\mu$ A
- TRANSPARENT 8-PIN DIP

### APPLICATIONS

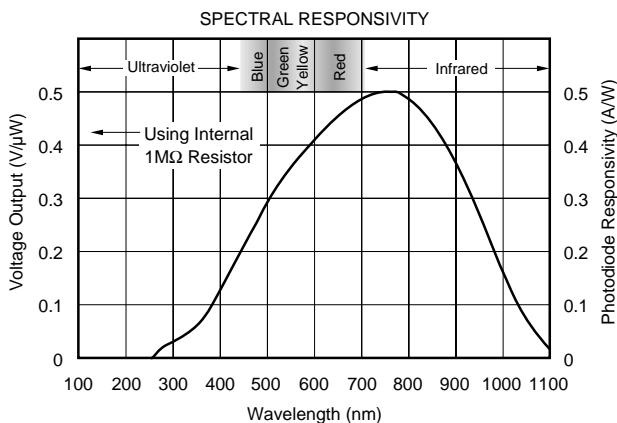
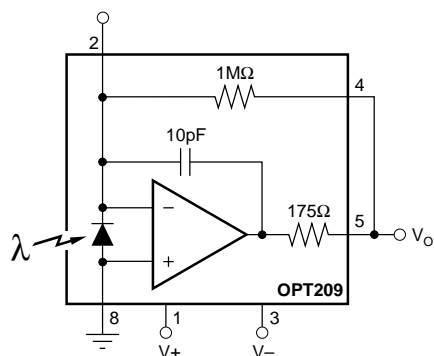
- MEDICAL INSTRUMENTATION
- LABORATORY INSTRUMENTATION
- POSITION AND PROXIMITY SENSORS
- PHOTOGRAPHIC ANALYZERS
- SMOKE DETECTORS

### DESCRIPTION

The OPT209 is an opto-electronic integrated circuit containing a photodiode and transimpedance amplifier on a single dielectrically isolated chip. The transimpedance amplifier consists of a precision FET-input op amp and an on-chip metal film resistor. The 0.09 x 0.09 inch photodiode is operated at zero bias for excellent linearity and low dark current.

The integrated combination of photodiode and transimpedance amplifier on a single chip eliminates the problems commonly encountered in discrete designs such as leakage current errors, noise pick-up and gain peaking due to stray capacitance.

The OPT209 operates over a wide supply range ( $\pm 2.25$  to  $\pm 18$ V) and supply current is only 400 $\mu$ A. It is packaged in a transparent plastic 8-pin DIP, specified for the 0°C to 70°C temperature range.



# SPECIFICATIONS

## ELECTRICAL

At  $T_A = +25^\circ\text{C}$ ,  $V_S = \pm 15\text{V}$ ,  $\lambda = 650\text{nm}$ , internal  $1\text{M}\Omega$  feedback resistor, unless otherwise noted.

PARAMETER	CONDITIONS	OPT209P			UNITS
		MIN	TYP	MAX	
<b>RESPONSIVITY</b> Photodiode Current Voltage Output vs Temperature Unit-to-Unit Variation Nonlinearity <sup>(1)</sup> Photodiode Area	650nm 650nm 650nm FS Output = 10V (0.090 x 0.090in) (2.29 x 2.29mm)		0.45 0.45 100 $\pm 5$ 0.01 0.008 5.2		A/W V/ $\mu\text{W}$ ppm/ $^\circ\text{C}$ % % of FS in <sup>2</sup> mm <sup>2</sup>
<b>DARK ERRORS, RTO<sup>(2)</sup></b> Offset Voltage, Output vs Temperature vs Power Supply Voltage Noise	$V_S = \pm 2.25\text{V}$ to $\pm 18\text{V}$ Measured BW = 0.1 to 100kHz		$\pm 0.5$ $\pm 10$ 10 350	$\pm 2$  100	mV $\mu\text{V}/^\circ\text{C}$ $\mu\text{V/V}$ $\mu\text{Vrms}$
<b>RESISTOR—1M<math>\Omega</math> Internal</b> Resistance Tolerance vs Temperature			1 $\pm 0.5$ 50	$\pm 2$	M $\Omega$ % ppm/ $^\circ\text{C}$
<b>FREQUENCY RESPONSE</b> Bandwidth, Large or Small-Signal, -3dB Rise Time, 10% to 90% Settling Time, 1% 0.1% 0.01% Overload Recovery Time (to 1%)	FS to Dark FS to Dark FS to Dark 100% Overdrive, $V_S = \pm 15\text{V}$ 100% Overdrive, $V_S = \pm 5\text{V}$ 100% Overdrive, $V_S = \pm 2.25\text{V}$		16 22 60 85 100 44 100 240		kHz $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$
<b>OUTPUT</b> Voltage Output Capacitive Load, Stable Operation Short-Circuit Current	$R_L = 10\text{k}\Omega$ $R_L = 5\text{k}\Omega$	(V+) - 1.25 (V+) - 2	(V+) - 1 (V+) - 1.5 1 $\pm 18$		V V nF mA
<b>POWER SUPPLY</b> Specified Operating Voltage Operating Voltage Range Quiescent Current	$V_O = 0$	$\pm 2.25$	$\pm 15$ $\pm 400$	$\pm 18$ $\pm 500$	V V $\mu\text{A}$
<b>TEMPERATURE RANGE</b> Specification, Operating Storage Thermal Resistance, $\theta_{JA}$		0 -25	100	+70 +85	$^\circ\text{C}$ $^\circ\text{C}$ $^\circ\text{C/W}$

NOTES: (1) Deviation in percent of full scale from best-fit straight line. (2) Referred to Output. Includes all error sources.

## PHOTODIODE SPECIFICATIONS

At  $T_A = +25^\circ\text{C}$ , unless otherwise noted.

PARAMETER	CONDITIONS	Photodiode of OPT209			UNITS
		MIN	TYP	MAX	
Photodiode Area	(0.090 x 0.090in) (2.29 x 2.29mm)		0.008 5.1		in <sup>2</sup> mm <sup>2</sup>
Current Responsivity	650nm		0.45		A/W
Dark Current vs Temperature	$V_D = 0\text{V}^{(1)}$		500 doubles every $10^\circ\text{C}$		fA
Capacitance	$V_D = 0\text{V}^{(1)}$		600		pF

NOTE: (1) Voltage Across Photodiode.

# SPECIFICATIONS (CONT)

## ELECTRICAL

## Op Amp Section of OPT209<sup>(1)</sup>

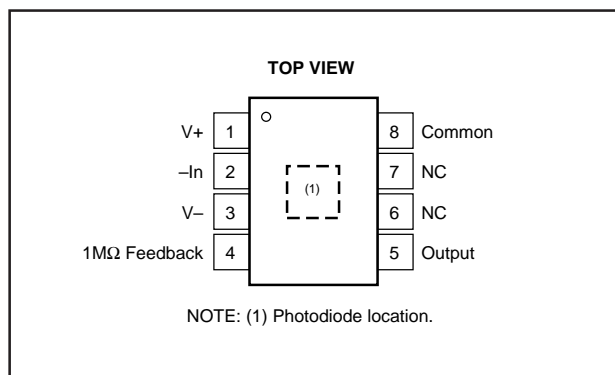
At  $T_A = +25^\circ\text{C}$ ,  $V_S = \pm 15\text{V}$ , unless otherwise noted.

PARAMETER	CONDITIONS	OPT209 Op Amp			UNITS
		MIN	TYP	MAX	
<b>INPUT</b> Offset Voltage vs Temperature vs Power Supply Input Bias Current vs Temperature	$V_S = \pm 2.25\text{V to } \pm 18\text{V}$		$\pm 0.5$ $\pm 5$ 10 1 doubles every $10^\circ\text{C}$		mV $\mu\text{V}/^\circ\text{C}$ $\mu\text{V/V}$ pA
<b>NOISE</b> Input Voltage Noise Voltage Noise Density, $f=10\text{Hz}$ $f=100\text{Hz}$ $f=1\text{kHz}$ Current Noise Density, $f=1\text{kHz}$			30 25 15 0.8		$\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$ $\text{fA}/\sqrt{\text{Hz}}$
<b>INPUT VOLTAGE RANGE</b> Common-Mode Input Range Common-Mode Rejection			$\pm 14.4$ 106		V dB
<b>INPUT IMPEDANCE</b> Differential Common-Mode			$10^{12}  3$ $10^{12}  3$		$\Omega  \text{pF}$ $\Omega  \text{pF}$
<b>OPEN-LOOP GAIN</b> Open-Loop Voltage Gain			120		dB
<b>FREQUENCY RESPONSE</b> Gain-Bandwidth Product Slew Rate Settling Time 0.1% 0.01%			4 6 4 5		MHz V/ $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$
<b>OUTPUT</b> Voltage Output Short-Circuit Current	$R_L = 10\text{k}\Omega$ $R_L = 5\text{k}\Omega$	$(V+) - 1.25$ $(V+) - 2$	$(V+) - 1$ $(V+) - 1.5$ $\pm 18$		V V mA
<b>POWER SUPPLY</b> Specified Operating Voltage Operating Voltage Range Quiescent Current	$I_O = 0$	$\pm 2.25$	$\pm 15$ $\pm 400$	$\pm 18$ $\pm 500$	V V $\mu\text{A}$

NOTE: (1) Op amp specifications provided for information and comparison only.

The information provided herein is believed to be reliable; however, BURR-BROWN assumes no responsibility for inaccuracies or omissions. BURR-BROWN assumes no responsibility for the use of this information, and all use of such information shall be entirely at the user's own risk. Prices and specifications are subject to change without notice. No patent rights or licenses to any of the circuits described herein are implied or granted to any third party. BURR-BROWN does not authorize or warrant any BURR-BROWN product for use in life support devices and/or systems.

## PIN CONFIGURATION



## ABSOLUTE MAXIMUM RATINGS

Supply Voltage .....	±18V
Input Voltage Range (Common Pin) .....	±V <sub>S</sub>
Output Short-Circuit (to ground) .....	Continuous
Operating Temperature .....	-25°C to +85°C
Storage Temperature .....	-25°C to +85°C
Junction Temperature .....	+85°C
Lead Temperature (soldering, 10s) .....	+300°C
(Vapor-Phase Soldering Not Recommended)	

## PACKAGE INFORMATION

PRODUCT	PACKAGE	PACKAGE DRAWING NUMBER <sup>(1)</sup>
OPT209P	8-Pin DIP	006-1
OPT209P-J	8-Lead Surface Mount <sup>(2)</sup>	006-4

NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix C of Burr-Brown IC Data Book. (2) 8-Pin DIP with leads formed for surface mounting.



## ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Burr-Brown recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



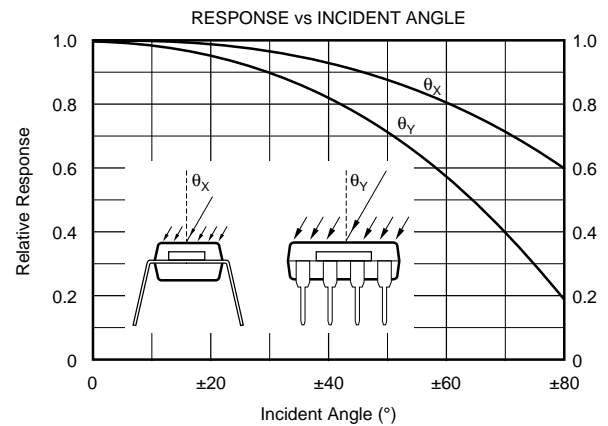
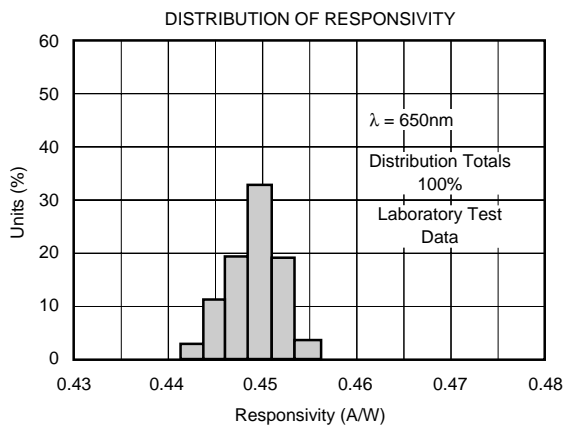
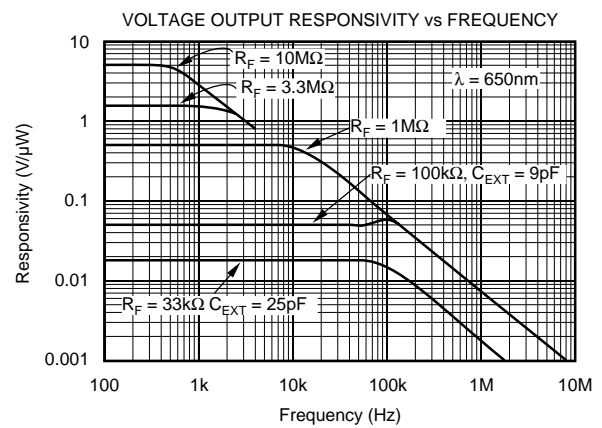
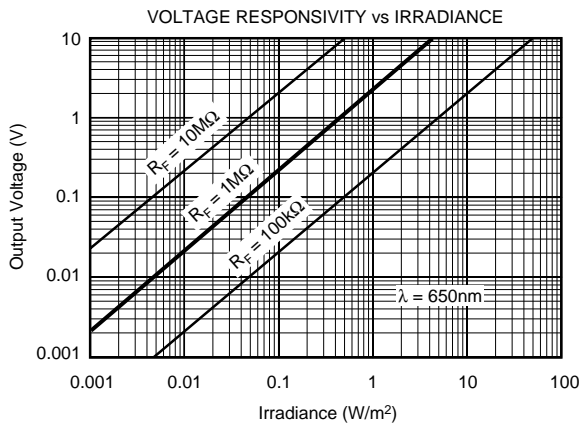
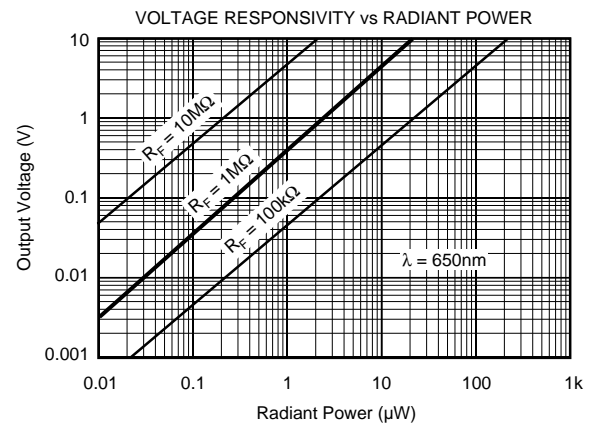
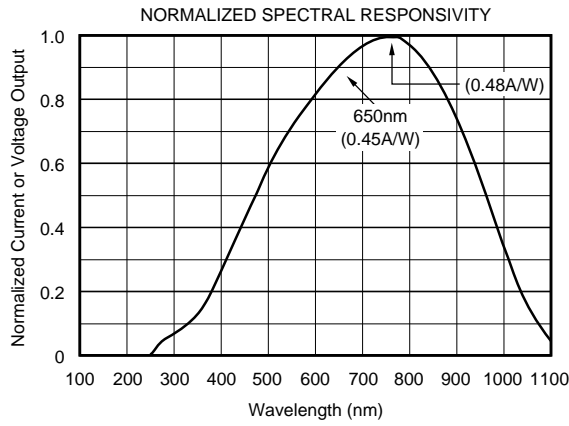
## MOISTURE SENSITIVITY AND SOLDERING

Clear plastic does not contain the structural-enhancing fillers used in black plastic molding compound. As a result, clear plastic is more sensitive to environmental stress than black plastic. This can cause difficulties if devices have been stored in high humidity prior to soldering. The rapid heating during soldering can stress wire bonds and cause failures. Prior to soldering, it is recommended that devices be baked-out at 85°C for 24 hours.

The fire-retardant fillers used in black plastic are not compatible with clear molding compound. The OPT209 cannot meet flammability test, UL-94.

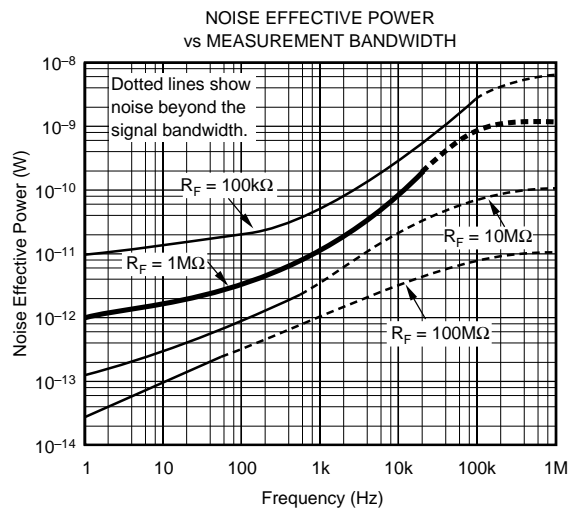
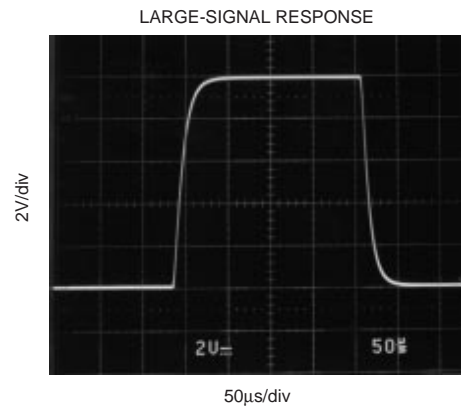
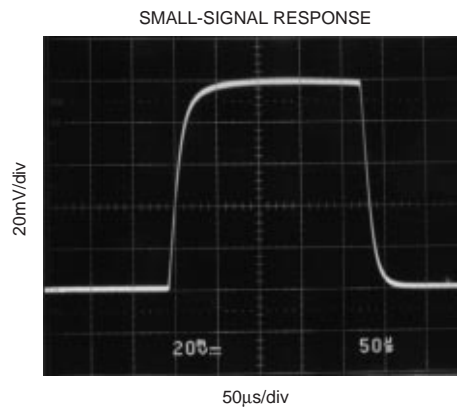
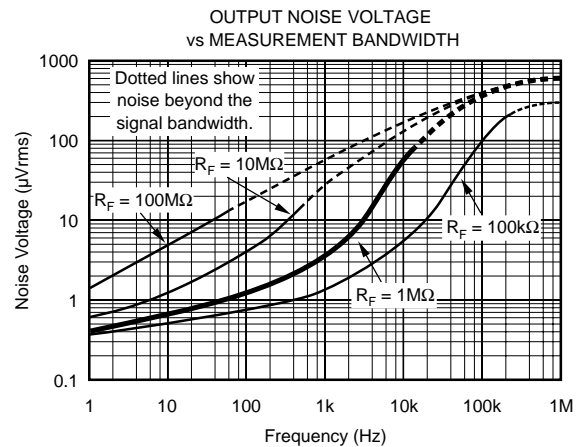
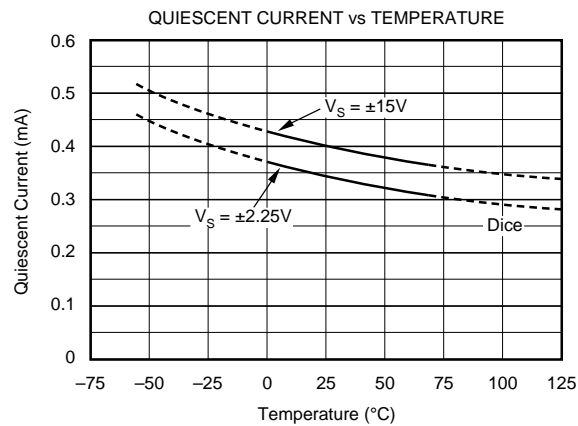
# TYPICAL PERFORMANCE CURVES

At  $T_A = +25^\circ\text{C}$ ,  $V_S = \pm 15\text{V}$ ,  $\lambda = 650\text{nm}$ , unless otherwise noted.



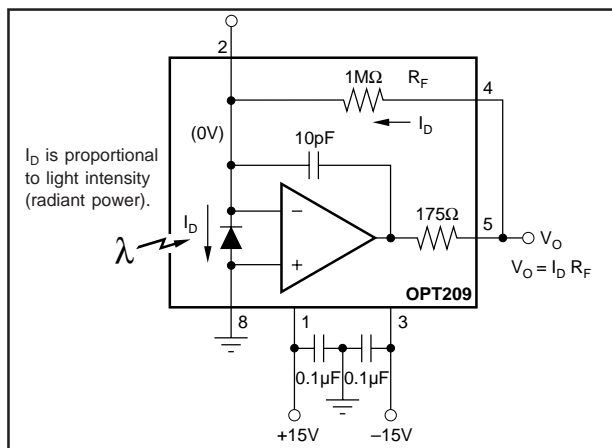
# TYPICAL PERFORMANCE CURVES (CONT)

At  $T_A = +25^\circ\text{C}$ ,  $V_S = \pm 15\text{V}$ ,  $\lambda = 650\text{nm}$ , unless otherwise noted.



## APPLICATIONS INFORMATION

Figure 1 shows the basic connections required to operate the OPT209. Applications with high-impedance power supplies may require decoupling capacitors located close to the device pins as shown. Output is zero volts with no light and increases with increasing illumination.



## DARK ERRORS

The dark errors in the specification table include all sources. The dominant error source is the input offset voltage of the op amp. Photodiode dark current and input bias current of the op amp are in the 2pA range and contribute virtually no offset error at room temperature. Dark current and input bias current double for each 10°C above 25°C. At 70°C, the error current can be approximately 100pA. This would produce a 1mV offset with  $R_F = 10\text{M}\Omega$ . The OPT209 is useful with feedback resistors of 100M $\Omega$  or greater at room temperature. The dark output voltage can be trimmed to zero with the optional circuit shown in Figure 3.

When used with very large feedback resistors, tiny leakage currents on the circuit board can degrade the performance of the OPT209. Careful circuit board design and clean assembly procedures will help achieve best performance. A “guard ring” on the circuit board can help minimize leakage to the critical non-inverting input (pin 2). This guard ring should encircle pin 2 and connect to Common, pin 8.

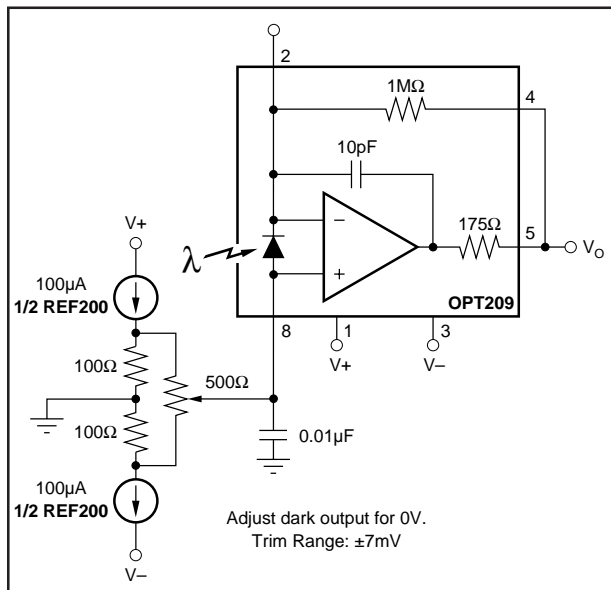


FIGURE 3. Dark Error (Offset) Adjustment Circuit.

## LINEARITY PERFORMANCE

Current output of the photodiode is very linear with radiant power throughout a wide range. Nonlinearity remains below approximately 0.01% up to 100μA photodiode current. The photodiode can produce output currents of 10mA or greater with high radiant power, but nonlinearity increases to several percent in this region.

This very linear performance at high radiant power assumes that the full photodiode area is uniformly illuminated. If the light source is focused to a small area of the photodiode, nonlinearity will occur at lower radiant power.

## DYNAMIC RESPONSE

Using the internal 1M $\Omega$  resistor, the dynamic response of the photodiode/op amp combination can be modeled as a

simple R/C circuit with a -3dB cutoff frequency of 16kHz. This yields a rise time of approximately 22μs (10% to 90%). Dynamic response is not limited by op amp slew rate. This is demonstrated by the dynamic response oscilloscope photographs showing virtually identical large-signal and small-signal response.

Dynamic response will vary with feedback resistor value as shown in the typical performance curve “Voltage Output Responsivity vs Frequency.” Rise time (10% to 90%) will vary according to the -3dB bandwidth produced by a given feedback resistor value—

$$t_R \approx \frac{0.35}{f_C} \quad (1)$$

where:

$t_R$  is the rise time (10% to 90%)

$f_C$  is the -3dB bandwidth

## NOISE PERFORMANCE

Noise performance of the OPT209 is determined by the op amp characteristics in conjunction with the feedback components and photodiode capacitance. The typical performance curve “Output Noise Voltage vs Measurement Bandwidth” shows how the noise varies with  $R_F$  and measured bandwidth (1Hz to the indicated frequency). The signal bandwidth of the OPT209 is indicated on the curves. Noise can be reduced by filtering the output with a cutoff frequency equal to the signal bandwidth.

Output noise increases in proportion to the square-root of the feedback resistance, while responsivity increases linearly with feedback resistance. So best signal-to-noise ratio is achieved with large feedback resistance. This comes with the trade-off of decreased bandwidth.

The noise performance of a photodetector is sometimes characterized by Noise Effective Power (NEP). This is the radiant power which would produce an output signal equal to the noise level. NEP has the units of radiant power (watts). The typical performance curve “Noise Effective Power vs Measurement Bandwidth” shows how NEP varies with  $R_F$  and measurement bandwidth.

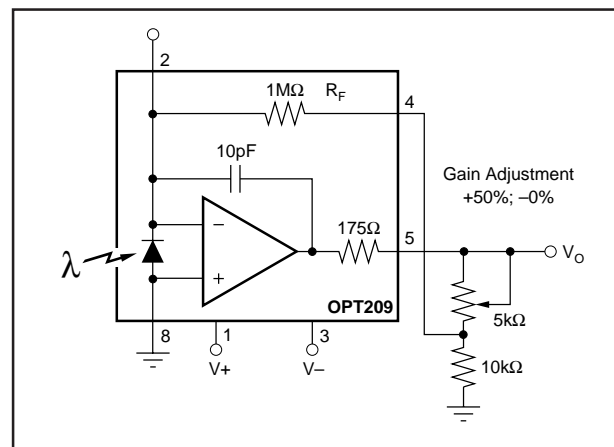


FIGURE 4. Responsivity (Gain) Adjustment Circuit.

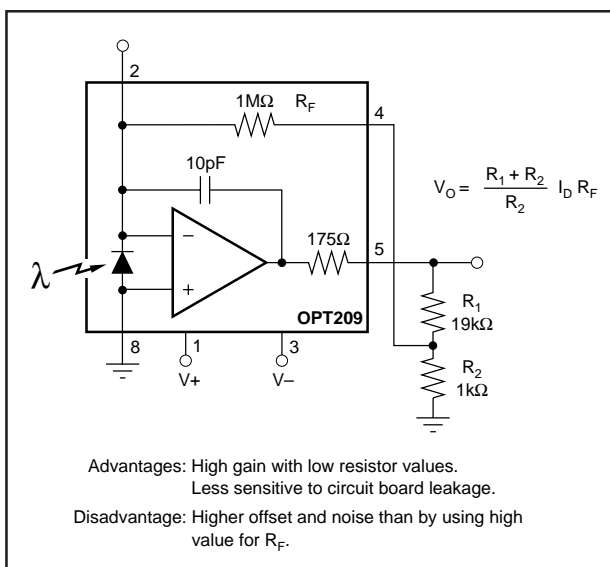


FIGURE 5. "T" Feedback Network.

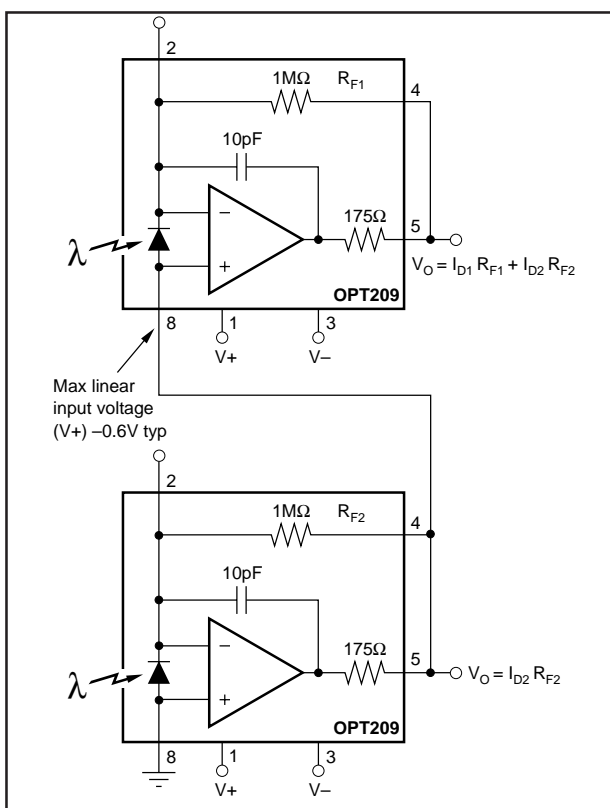


FIGURE 6. Summing Output of Two OPT209s.

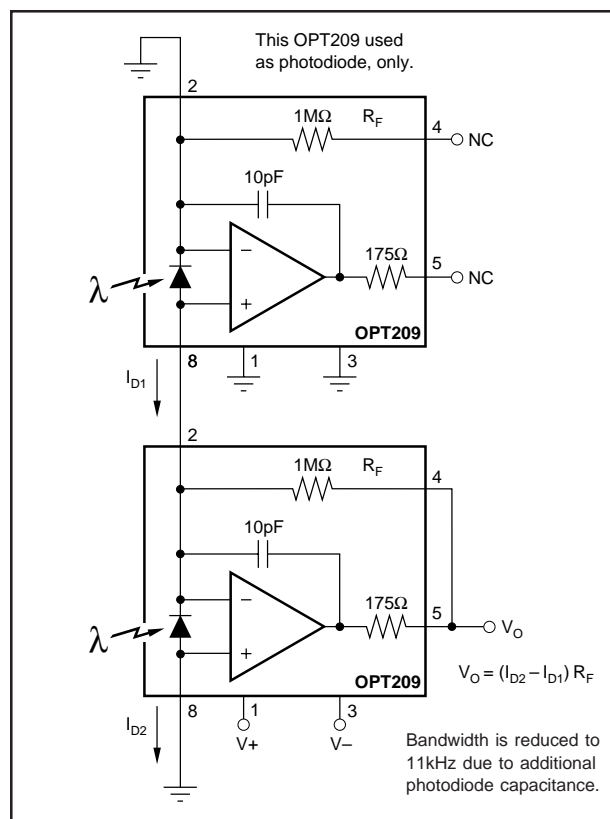


FIGURE 7. Differential Light Measurement.

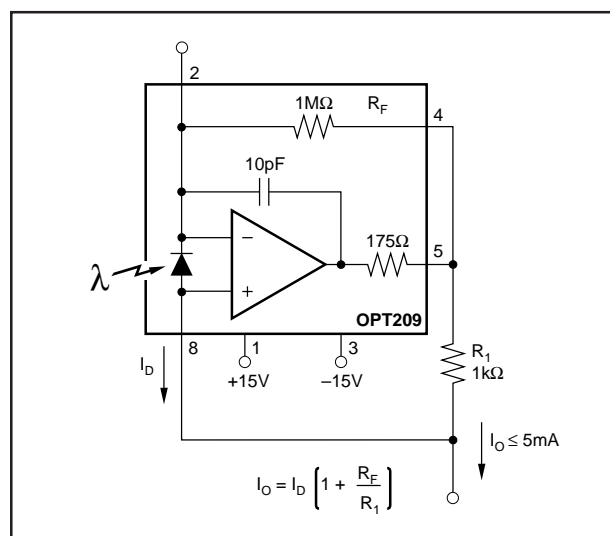


FIGURE 8. Current Output Circuit.

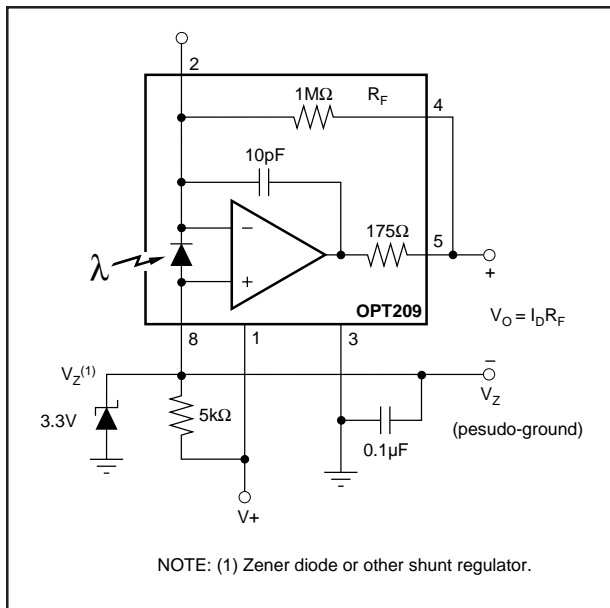


FIGURE 9. Single Power Supply Operation.

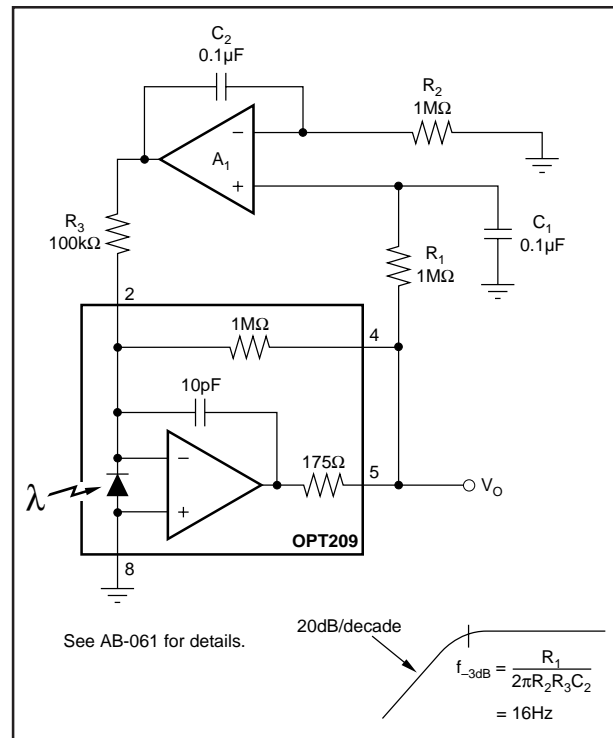


FIGURE 10. DC Restoration Rejects Unwanted Steady-State Background Light.

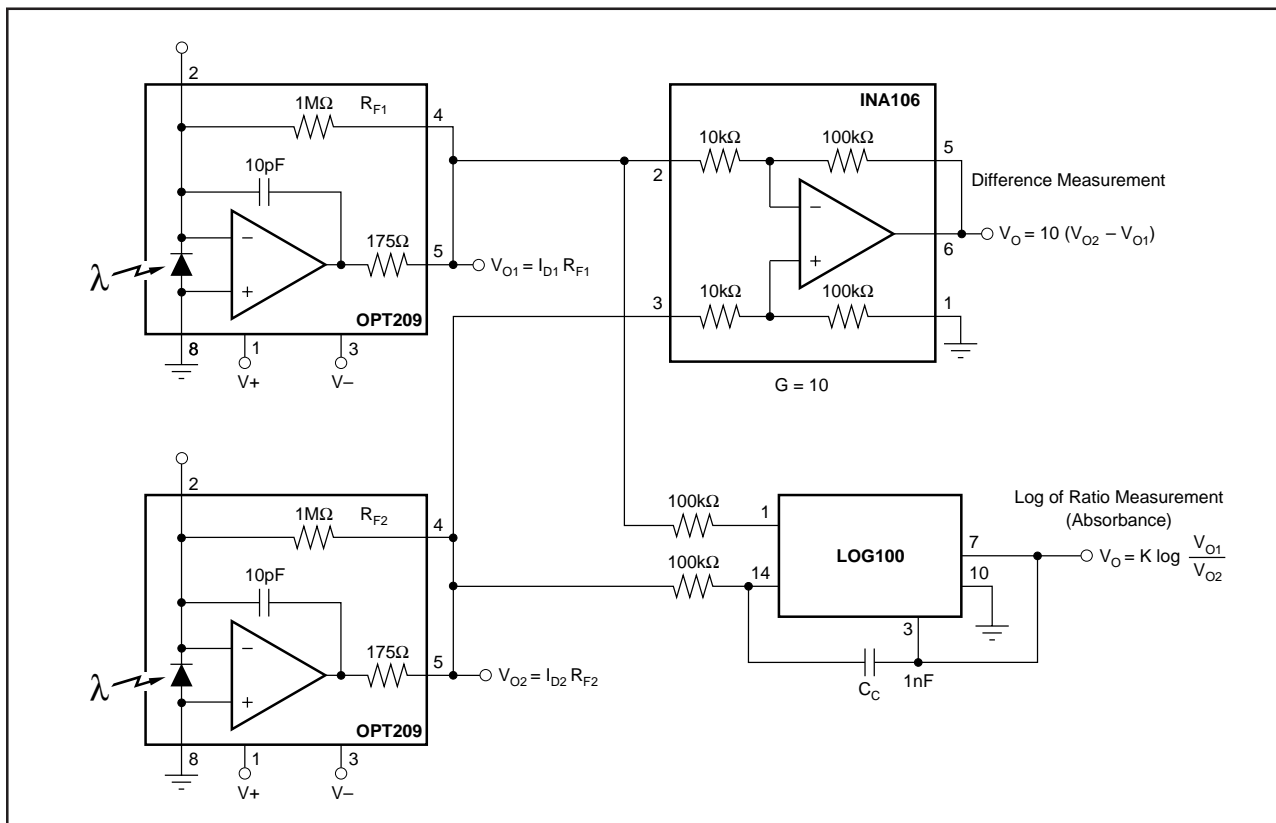


FIGURE 11. Differential Light Measurement.

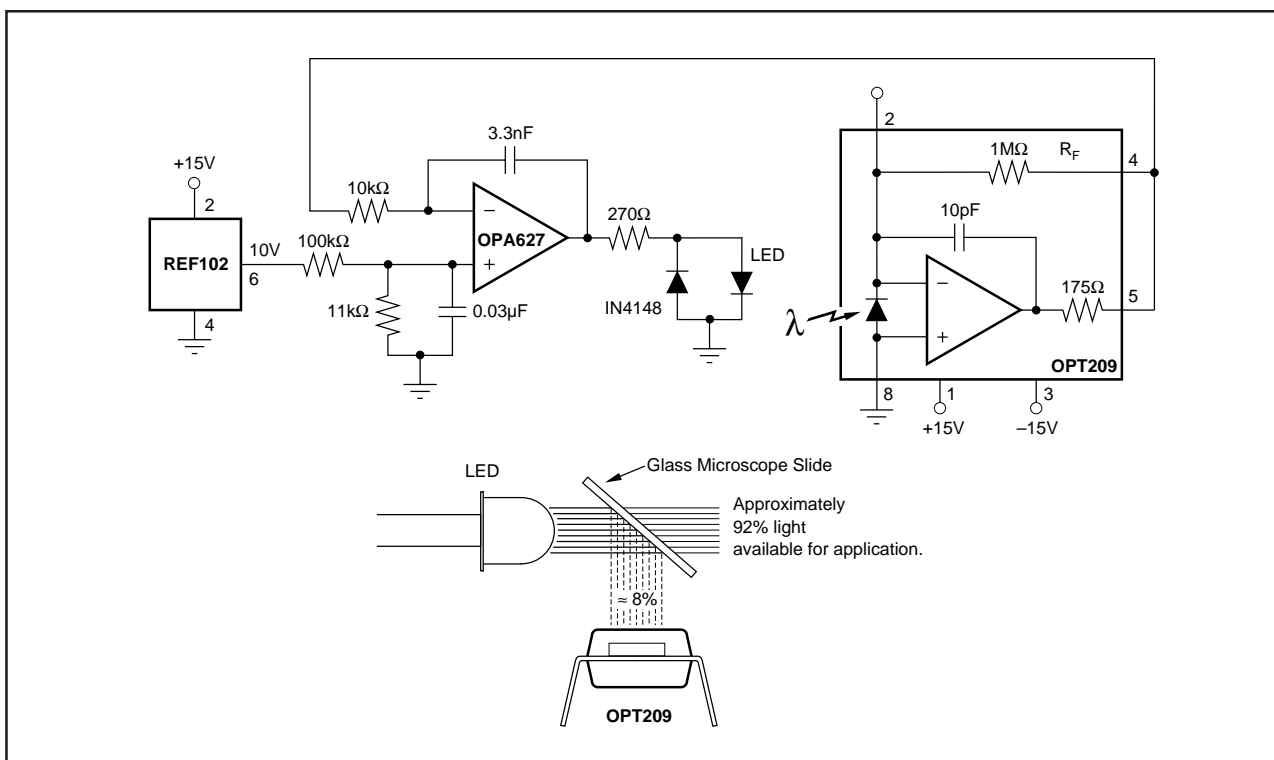


FIGURE 12. LED Output Regulation Circuit.

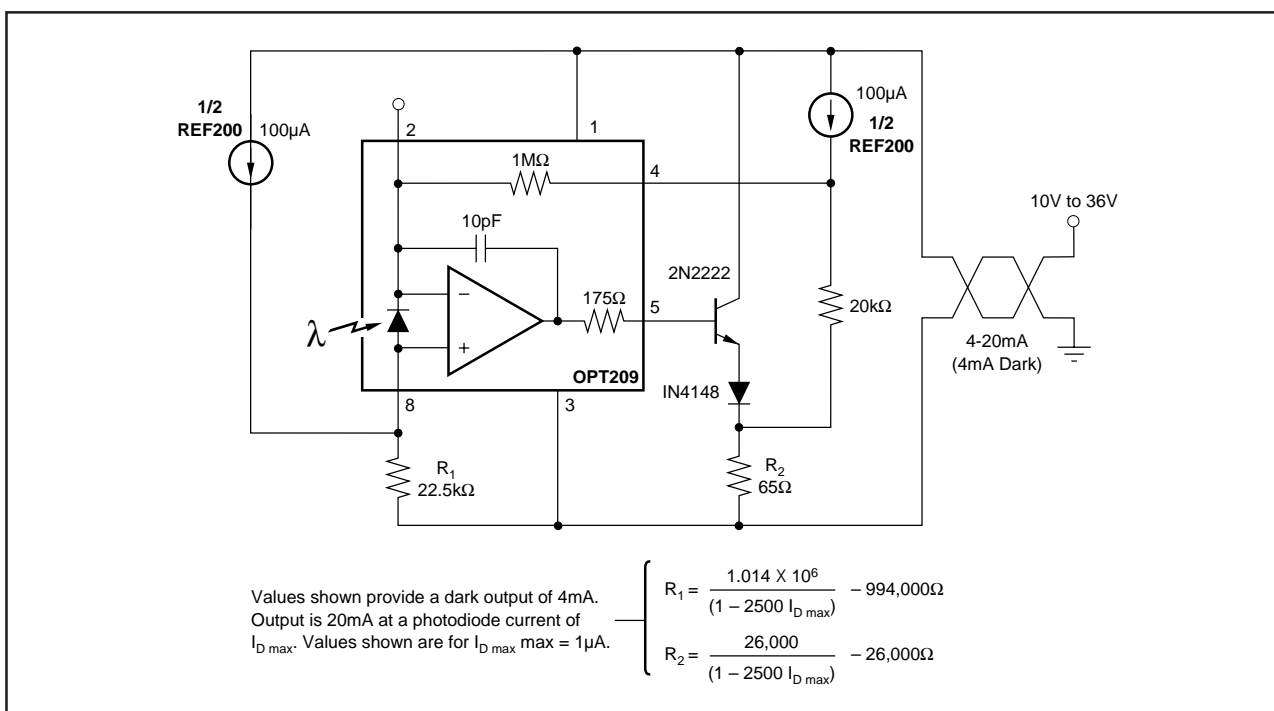


FIGURE 13. 4-20mA Current-Loop Transmitter.